

G(1

D²PAK

C

B

pin 1.Gate 2.Drain

3. Source

TO-263 package

isc N-Channel Mosfet Transistor

STB18NM60N

o D(2)

S(3)

S

- FEATURES
- Drain Current I_D= 13A@ T_C=25 $^\circ\!\!\mathrm{C}$
- Drain Source Voltage-

: V_{DSS}= 600V(Min)

- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT		
V _{DSS}	Drain-Source Voltage	600	V		
V_{GS}	Gate-Source Voltage	±25	V		
ID	Drain Current-continuous@ T _C =25℃	13	A		
I _{DM}	Pulse Drain Current	52	A		
P _{tot}	Total Dissipation@T _C =25℃	110	W		
Tj	Max. Operating Junction Temperature	150	°C		
T _{stg}	Storage Temperature Range	-55~150	°C		
• THERMAL CHARACTERISTICS					
		1	1		

PARAMETER

Thermal Resistance, Junction to Case

	K		
D		Q	U
H	1	R	V
	m	m]
DIM	MIN	MAX	
A	1	0	
В	6.6	6.8	1
C			
	15.23	15.25	1
D		15.25	-
D	15.23	15.25 10.17 0.78	-

В	0.0	0.0	
C	15.23	15.25	
D	10.15	10.17	
F	0.76	0.78	
G	1.26	1.28	
H	1.4	1.6	
J	1.33	1.35	
K	0.4	0.6	ί
L	4.6	4.8	
0	8.69	8.71	
R	5.28	5.30	
S	1.26	1.28	2
U	0.0	0.2	
V	0.37	0.39	
W	2.80	2.82	ĵ.

isc website: www.iscsemi.com

SYMBOL

Rth j-c

isc & iscsemi is registered trademark

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MAX

1.14

UNIT

°C/W



isc N-Channel Mosfet Transistor

STB18NM60N

ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25\,^{\circ}\!\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 1mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250µA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 6.5A			285	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±25V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = Max rating			1	μΑ
		V _{DS} = Max rating; T _C =125℃			10	
V _{SD}	Diode Forward On-Voltage	I _S = 13A ;V _{GS} = 0			1.6	V

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